

3P4MH, 3P6MH

3 A MOLD SCR

The 3P4MH and 3P6MH are P-gate fully diffused mold SCRs with an average on-current of 3 A. The repeat peak off-voltages (and reverse voltages) are 400 V and 600 V.

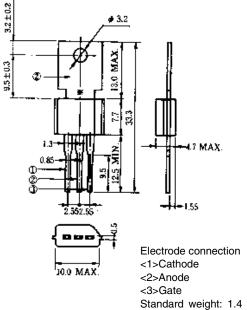
FEATURES

- This transistor features a small and lightweight package and is easy to handle even on the mounting surface due to its TO-202AA dimensions. Processing of lead wires and heatsink (tablet) using jigs is also possible.
- Employs flame-retardant epoxy resin (UL94V-0).

APPLICATIONS

Noncontact switches of consumer electronic euipments, electric equipments, audio quipments, and light indutry equipments

PACKAGE DRAWING (UNIT: mm)



*TC test bench-mark

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	3P4MH	3Р6МН	Ratings	Unit
Non-repetitive peak reverse voltage	Vrsm	500	700	V	$R_{GK} = 1 k\Omega$
Non-repetitive peak off-state voltage	V _{DSM}	500	700	٧	$R_{GK} = 1 k\Omega$
Repetitive peak reverse voltage	V _{RRM}	400	600	٧	$R_{GK} = 1 k\Omega$
Repetitive peak off-voltage	V _{DRM}	400	600	V	$R_{GK} = 1 k\Omega$
Average on-state current	I _{T(AV)}	3 (Tc = 87°C, Single	Α	Refer to Figure 11.	
Effective on-state current	I _{T(RMS)}	4	Α	-	
Surge on-state current	Ітѕм	65 (f = 50 Hz, Sine half-wave, 1 cycle) 70 (f = 60 Hz, Sine half-wave, 1 cycle)		Α	Refer to Figure 2.
Fusing current	∫it²dt	20 (1 ms:	A ² s	-	
Critical rate of rise of on-state current	dl⊤/dt	50		A/μs	-
Peak gate power dissipation	Рам	2 (f≥50 Hz, Duty≤10%)		W	Refer to Figure 3.
Average gate power dissipation	P _{G(AV)}	0	W		
Peak gate forward current	lгдм	1 (f≥50 Hz,	Α	-	
Peak gate reverse voltage	Vrgm	6		V	-
Junction temperature	Tj	–40 to	°C	-	
Storage temperature	T _{stg}	−55 tp	°C	-	

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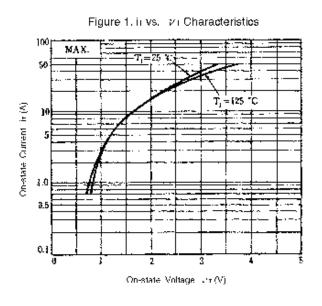
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

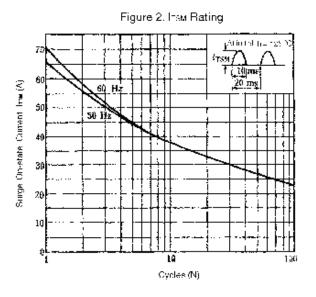


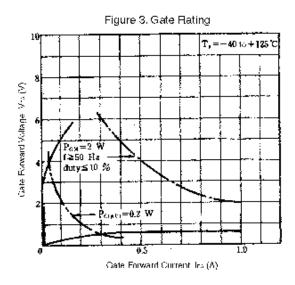
ELECTRICAL CHARACTERISTICS (Tj = 25°C, Rg κ = 1 k Ω)

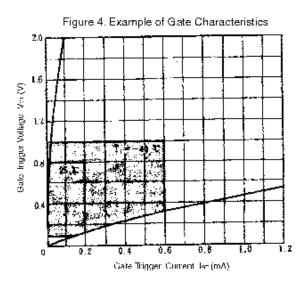
Parameter	Symbol	Conditions		Specifications			Unit	Remarks
				MIN.	TYP.	MAX.		
Repeat peak reverse current	IRRM	V _{RM} = V _{RRM}	T _j = 25°C	-	-	100	μΑ	_
			T _j = 125°C	-	-	2	mA	_
Repeat peak off-current	IDRM	V _{DM} = V _{DRM}	T _j = 25°C	-	-	100	μΑ	_
			T _j = 125°C	_	-	2	mA	_
Critical rate-of-rise of off- state voltage	dV/dt	$T_j = 125^{\circ}C, V_{DM} = \frac{2}{3}V_{DRM}$		_	3	_	V/μs	_
On-state voltage	Vтм	Iτ = 10 A		_	-	1.6	V	Refer to Figure 1.
Gate trigger current	Іст	$V_{DM} = 6 \text{ V}, \text{ RL} = 100 \Omega$		_	-	0.2	mA	Refer to Figure 14.
Gate trigger voltage	V GT	$V_{DM} = 6 \text{ V}, \text{ RL} = 100 \Omega$		_	-	0.8	V	
Gate non-trigger voltage	V _{GD}	$T_{j} = 125^{\circ}C,$ $V_{DM} = \frac{V_{DRM}}{2}$		0.2	_	-	V	-
Holding current	Ін	V _{DM} = 24 V, I _{TM} = 10 A		-	1	5	mA	-
Commutating turn-off time	Tq	$T_{\rm J} = 125^{\circ}{\rm C},$ $I_{\rm T} = 3$ A, dia/dt = 15 A/μs $V_{\rm R} \ge 25$ V, $V_{\rm DM} = \frac{2}{3}V_{\rm DRM}$ $dV_{\rm D}/dt = 1$ V/μs		_	80	-	μs	-
Thermal resistance	Rth(j-c)	Junction-to-case DC Junction-to-ambient DC		-	-	8	°C/W	Refer to Figure 13.
	R _{th(j-a)}			_	_	75		

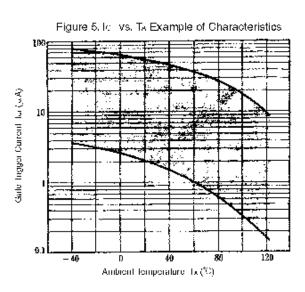
TYPICAL CHARACTERISTICS (Ta = 25°C)

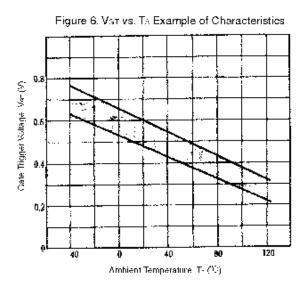


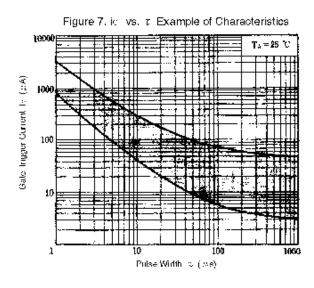


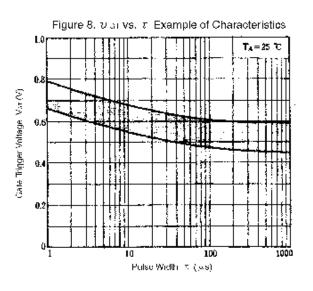




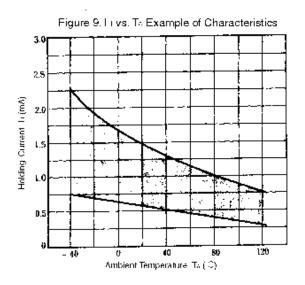


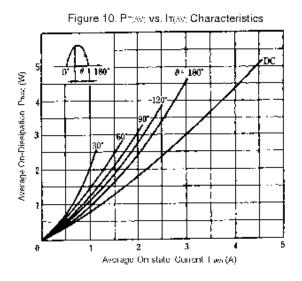


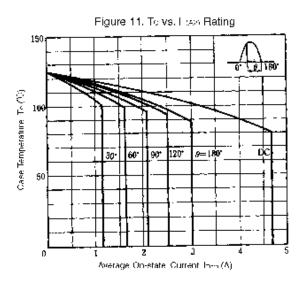


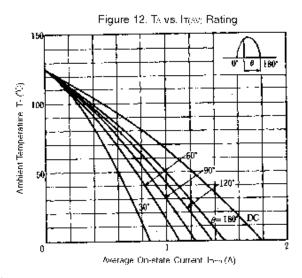


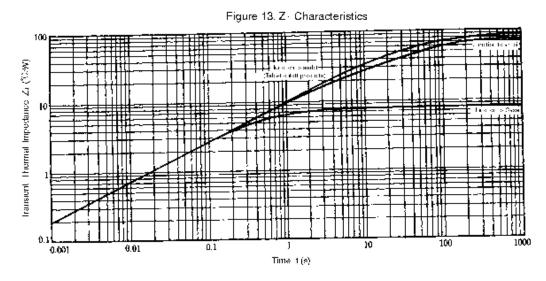
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[MEMO]

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